RoHS

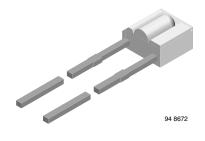
HALOGEN FREE

GREEN



## Vishay Semiconductors

# Infrared Emitting Diode, 950 nm, GaAs

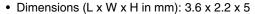


### DESCRIPTION

TSSS2600 is an infrared, 950 nm emitting diode in GaAs technology, molded in a miniature, clear plastic package with side view lens.

#### **FEATURES**

Package type: leadedPackage form: side view



Peak wavelength: λ<sub>p</sub> = 950 nm

High reliability

· High radiant power

· High radiant intensity

• Angle of half intensity:  $\varphi = \pm 25^{\circ}$ , horizontal

· Low forward voltage

· Suitable for high pulse current operation

· Good spectral matching with Si photodetectors

Package matched with detector TEST2600

 Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>



 Infrared source in miniature light barriers or reflective sensor systems with short transmission distances and low forward voltage requirements. Matching with silicon PIN photodiodes or phototransistors (e.g. TEST2600)

PRODUCT SUMMARY					
COMPONENT	I <sub>e</sub> (mW/sr)	φ <b>(°)</b>	$λ_{\mathbf{p}}$ (nm)	t <sub>r</sub> (ns)	
TSSS2600	2.6	± 25	950	800	

#### Note

• Test conditions see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
TSSS2600	Bulk	MOQ: 5000 pcs, 5000 pcs/bulk	Side view	

#### Note

· MOQ: minimum order quantity

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		$V_{R}$	5	V	
Forward current		I <sub>F</sub>	100	mA	
Peak forward current	$t_p/T = 0.5, t_p = 100 \mu s$	I <sub>FM</sub>	200	mA	
Surge forward current	t <sub>p</sub> = 100 μs	I <sub>FSM</sub>	2.0	А	
Power dissipation		P <sub>V</sub>	170	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T <sub>amb</sub>	- 40 to + 100	°C	
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C	
Soldering temperature	$t \le 5$ s, 2 mm from case	T <sub>sd</sub>	260	°C	
Thermal resistance junction/ambient	Leads not soldered	R <sub>thJA</sub>	450	K/W	





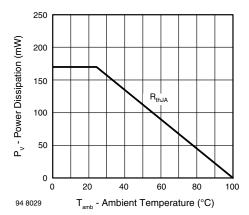


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

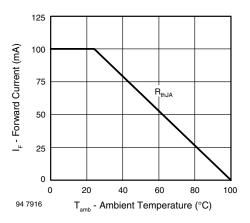


Fig. 2 - Forward Current Limit vs. Ambient Temperature

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	$V_{F}$		1.25	1.6	V
	$I_F = 1.5 \text{ A}, t_p = 100 \mu\text{s}$	$V_{F}$		2.2		V
Temperature coefficient of V <sub>F</sub>	I <sub>F</sub> = 100 mA	TK <sub>VF</sub>		- 1.3		mV/K
Reverse current	V <sub>R</sub> = 5 V	I <sub>R</sub>			100	μΑ
Junction capacitance	V <sub>R</sub> = 0 V, f = 1 MHz, E = 0	C <sub>j</sub>		30		pF
Radiant intensity	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l <sub>e</sub>	1	2.6	3	mW/sr
	$I_F = 1.5 \text{ A}, t_p = 100 \mu\text{s}$	l <sub>e</sub>		25		mW/sr
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	фe		20		mW
Temperature coefficient of φ <sub>e</sub>	I <sub>F</sub> = 100 mA	TKφ <sub>e</sub>		- 0.8		%/K
Angle of half intensity	horizontal	Ψ1		± 25		0
	vertical	φ <sub>2</sub>		± 60		0
Peak wavelength	I <sub>F</sub> = 100 mA	$\lambda_{p}$		950		nm
Spectral bandwidth	I <sub>F</sub> = 100 mA	Δλ		50		nm
Temperature coefficient of $\lambda_p$	I <sub>F</sub> = 100 mA	TKλ <sub>p</sub>		0.2		nm/K
Rise time	I <sub>F</sub> = 100 mA	t <sub>r</sub>		800		ns
	I <sub>F</sub> = 1.5 A	t <sub>r</sub>		400		ns
Eall Kinns	I <sub>F</sub> = 100 mA	t <sub>f</sub>		800		ns
Fall time	I <sub>F</sub> = 1.5 A	t <sub>f</sub>		400		ns
Virtual source diameter		d		2		mm

## Vishay Semiconductors

### **BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

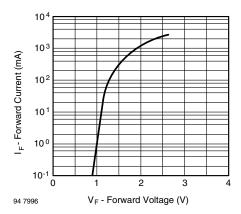


Fig. 3 - Pulse Forward Current vs. Forward Voltage

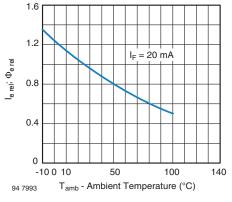


Fig. 6 - Relative Radiant Intensity/Power vs. Ambient Temperature

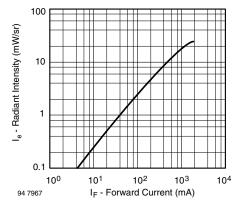


Fig. 4 - Radiant Intensity vs. Forward Current

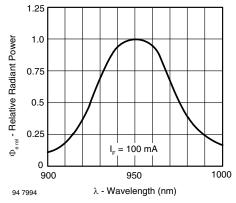


Fig. 7 - Relative Radiant Power vs. Wavelength

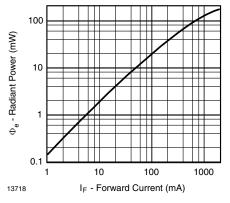


Fig. 5 - Radiant Power vs. Forward Current

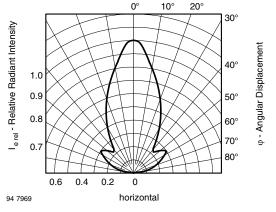


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement





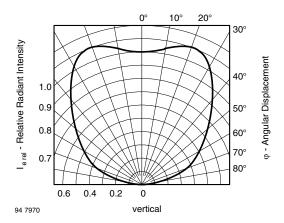
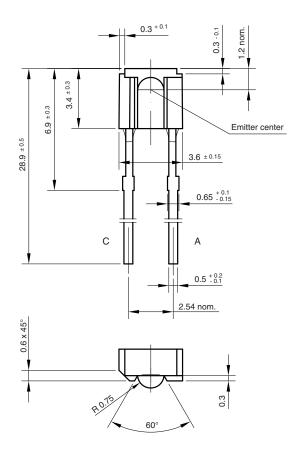


Fig. 1 - Relative Radiant Intensity vs. Angular Displacement

### **PACKAGE DIMENSIONS** in millimeters



Area not plane

1.8 ± 0.15

2.2 ± 0.15

0.4 + 0.15

technical drawings

according to DIN specifications

Drawing-No.: 6.544-5241.01-4

Issue: 3; 18.04.96

95 11488



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